RENESAS

HD74LS258

Quadruple 2-line-to-1-line Data Selectors / Multiplexers (with three-state outputs)

REJ03D0470-0300 Rev.3.00 Jul.15.2005

This multiplexer features three-state outputs that can interface directly with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state) the low impedance of the single enabled output will drive the bus line to a high or low logic level.

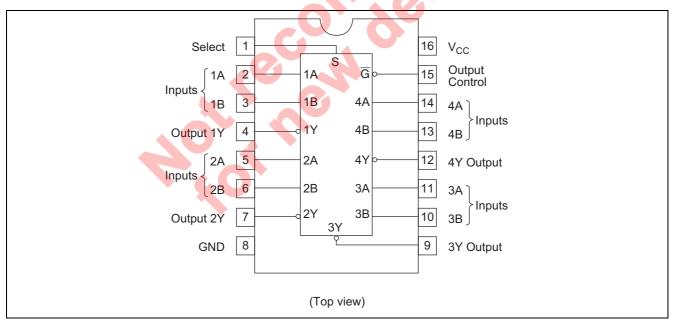
To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the output enable circuitry is designed such that the output disable times are shorter than the output enable times.

Features

• Ordering Information

Part Name	Package Type	Package Code Package (Previous Code) Abbreviation		Taping Abbreviation (Quantity)	
HD74LS258FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)	

Pin Arrangement



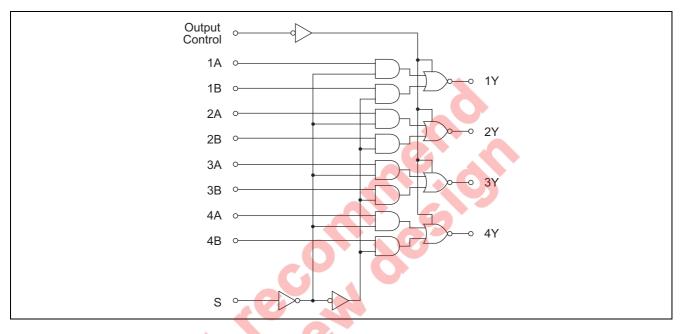


Function Table

	Output			
OC	S	Α	В	Y
Н	Х	Х	Х	Z
L	L	L	Х	Н
L	L	Н	Х	L
L	Н	Х	L	Н
L	Н	Х	Н	L

Note: H; high level, L; low level, X; irrelevant, Z; off (high-impedance) state of a 3-state output

Block Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{cc}	7	V
Input voltage	V _{IN}	7	V
Power dissipation	P _T	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{CC}	4.75	5.00	5.25	V
Output current	I _{OH}	—		-2.6	mA
Output current	I _{OL}	—	_	8	mA
Operating temperature	Topr	-20	25	75	°C



Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \ ^{\circ}\text{C})$

ltem		Symbol	min.	typ.*	max.	Unit	Condition
Input voltage		V _{IH}	2.0	—	—	V	
		V _{IL}	_	—	0.8	V	
		V _{он}	2.4	_	_	V	$\label{eq:VCC} \begin{split} V_{CC} &= 4.75 \ \text{V}, \ \text{V}_{\text{IH}} = 2 \ \text{V}, \ \text{V}_{\text{IL}} = 0.8 \ \text{V}, \\ I_{OH} &= -2.6 \ \text{mA} \end{split}$
Output vol	lage	V	_	_	0.4	V	$I_{OL} = 4 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, \text{ V}_{IH} = 2 \text{ V},$
		V _{OL}	_	—	0.5	V	$I_{OL} = 8 \text{ mA}$ $V_{IL} = 0.8 \text{ V}$
	rront	I _{OZH}	_	—	20	μΑ	$V_{CC} = 5.25 \text{ V}, V_{IH} = 2 \text{ V}, V_O = 2.4 \text{ V}$
Output Cu	irent	I _{OZL}	_	—	-20	μΑ	$V_{CC} = 5.25 \text{ V}, \text{ V}_{IH} = 2 \text{ V}, \text{ V}_{O} = 0.4 \text{ V}$
	S	IIH		—	40	μΑ	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$
	except S		_	—	20	μΑ	$v_{CC} = 5.25 v, v_1 = 2.7 v$
Input	S	1	_	—	-0.8	mA	V _{CC} = 5.25 V, V _I = 0.4 V
current	except S	IIL	_	—	-0.4	mA	$v_{\rm CC} = 5.25 v, v_{\rm I} = 0.4 v$
	S	1	_	—	0.2	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$
	except S	I,	_	—	0.1	mA	$v_{CC} = 5.25 v, v_1 = 7 v$
Short-circu	it output current	I _{OS}	-30	—	-130	mA	$V_{CC} = 5.25 V$
Supply current**	All outputs high	lcc	_	—	7	mA	
	All outputs low		_	—	11	mA	V _{cc} = 5.25 V
	All outputs off		_	—	12	mA	
Input clamp voltage		VIK	_		-1.5	V	$V_{CC} = 4.75 \text{ V}, \text{ I}_{IN} = -18 \text{ mA}$
NI (+) ($I = E M T_0 = 2E^{\circ}$	~					

Notes: * $V_{CC} = 5 V$, Ta = 25°C

** I_{CC} is measured with all outputs open and all possible inputs grounded while achieving the stated output conditions.

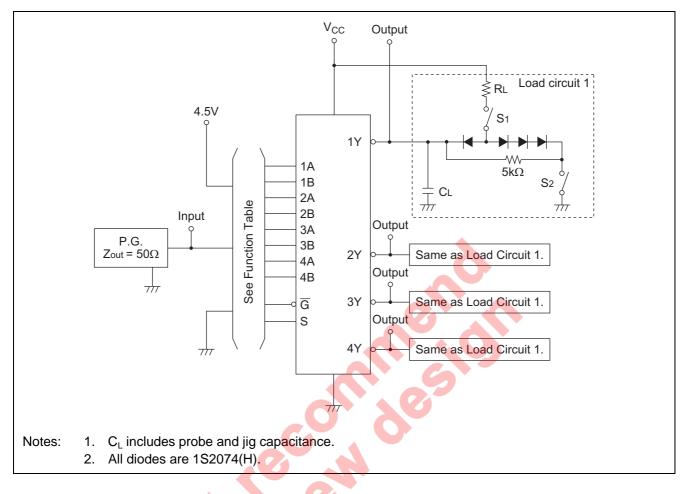
Switching Characteristics

		0					$(V_{CC} = 5)$	V, Ta = 25°C)
ltem	Symbol	Inputs	Output	min.	typ.	max.	Unit	Condition
	t _{PLH}	А, В	Y		12	18	ns	
Propagation delay time	t _{PHL}	А, Б			12	18	115	$C_L = 15 \text{ pF},$ $R_L = 2 \text{ k}\Omega$
	t _{PLH}	S	Y		14	21	ns	
	t _{PHL}				14	21		
Output onable time	t _{ZH}	OC	×		20	30	ns	
Output enable time	t _{ZL}		I	_	20	30	115	
Output disable time	t _{HZ}	ос	V	_	18	30	nc	$C_L = 5 \text{ pF},$
	t _{LZ}	▼ 00	ſ	_	16	25	ns	$R_L = 2 \ k\Omega$



Testing Method

Test Circuit



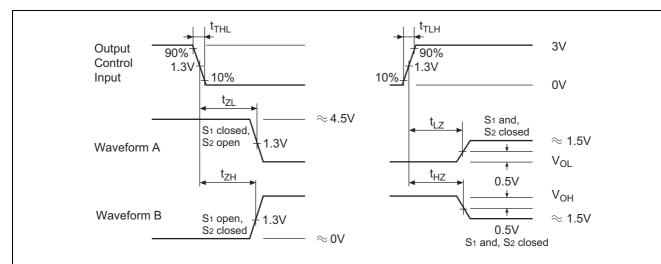
Waveforms 1

Input	10% t _{TLH} 10% t _{TLH} 1.3 V 1.3 V 1.3 V 1.3 V 1.3 V 1.3 V	- 3∨ - 0∨
Waveform A	S1 and S2 closed	– V _{OH} – V _{OL}
Waveform B	S1 and S2 closed	– V _{OH} – V _{OL}
Note: Input pulse; t	$_{TLH} \le 15$ ns, $t_{THL} \le 6$ ns, PRR = 1 MHz, duty cycle = 50%	



HD74LS258

Waveforms 2

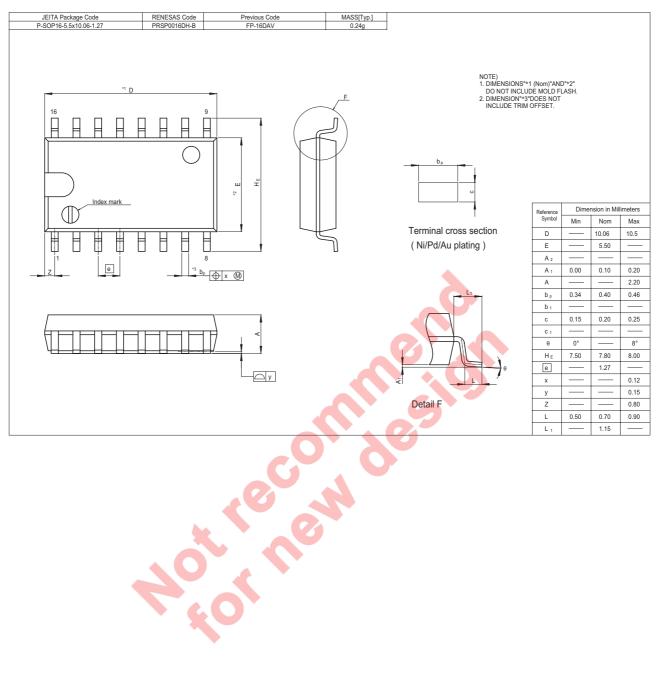


- Notes: 1. Input pulse; $t_{TLH} \le 15$ ns, $t_{THL} \le 6$ ns, PRR = 1 MHz, duty cycle = 50%
 - 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.

Rev.3.00, Jul.15.2005, page 5 of 6



Package Dimensions





Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs! 1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

- Notes regarding these materials
 These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.
 Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or oricruit application examples contained in these materials.
 All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. virbuut notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information described here may contain technical inaccuracies or typographical errors. Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors. Please also pay attention to information published by Renesas Technology Corp. by various means, including the Renesas Technology Corp. Semiconductor home page (http://www.renesas.com).
 When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, or genesas technology Corp. Semiconductor home page (http://www.renesas.com).

- Nome page (ntp://www.renesas.com).
 4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
 5. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- use. 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials. 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



http://www.renesas.com

RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. Unit2607 Ruijing Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510